

## **Particle Detectors**

A Lecture at the African School for Fundamental Physics and Applications, 28/11-09/12 2022 Nelson Mandela University, South Africa

### Lecture IV Advanced detectors and some new developments

First Workshop NextGAPES -2019 Lomonosov Moscow State University, Physics Department, Skobeltsyn Institute of Nuclear Physics. Moscow - June, 21-22, 2019 One example:

AMS100

Stefan Schael RWTH Aachen

CERN seminar 4-11-2022



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### **Particle Detectors**

Lecture at the African School for Fundamental Physics and Applications, 28/11-09/12 2022 Nelson Mandela University, South Africa Goal this lecture: to discuss some examples Looking at recent technological developments infinite number of ideas for new detectors

Lecture IV

- High purity segmented Ge-detectors for Nuclear physics
- LHC detectors
- Recent developments of CMOS pixel detectors
- Fast detectors for time of flight measurements
- High granularity calorimeters
- AMS100 in space

#### Exercises!!!!!







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#### PHOTO-ELECTRIC EFFECT

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Figure 1.3: Effect of interaction processes on the predicted detector response function for mono-energetic  $\gamma$ -rays with  $h\nu_0 >> 1.022 MeV$ .

COMPTON SCATTERING



PAIR CREATION











### Large volume semiconductor detector



## **Semi-conductor detectors**

			Mobility (velocity/E)					Z [a.m.u]
Material	E <sub>g</sub> [eV]	w [eV]		1	$\tau_{e}[s]$	$\tau_{h}[s]$	density	
			$\mu_{e}$	$\mu_h$			g/cm <sup>3</sup>	
			$[cm^2/Vs]$	[cm <sup>2</sup> /Vs]				
С	5.5	13	1800	1200	2 10 <sup>-9</sup>	<b>2</b> 10 <sup>-9</sup>	3.515	6
(diamond)								
Si	1.12	3.61	1350	480	5 10 <sup>-3</sup>	5 10 <sup>-3</sup>	2.33	14
Ge	0.67	2.98	3900	1900	2 10 <sup>-5</sup>	2 10 <sup>-5</sup>	5.32	32
GaAs	1.42	4.70	8500	450	5 10 <sup>-8</sup>	5 10 <sup>-8</sup>	5.32	31,33
CdTe	1.56	4.43	1050	100	1 10 <sup>-6</sup>	1 10 <sup>-6</sup>		48,52
HgI <sub>2</sub>	2.13	4.20	100	_	1 10 <sup>-6</sup>	2 10 <sup>-6</sup>		53,80

$$\frac{dN}{N} = \frac{1}{\sqrt{N}} ; E \sim N; \quad N = \text{numb. of (e,h)}$$

**Parameters Values for Materials Used in Fabricating Semiconductor Radiation Sensors** 



[3]

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## Large volume detectors

Depletion zone  

$$d\Big|_{V_{bias}} = x_n + x_p = \sqrt{\frac{2\varepsilon(\phi_0 + V_{bias})(N_A + N_D)}{e}} \frac{(N_A + N_D)}{N_A N_D}$$

$$N = N_A \ll N_D; \ \phi_0 \ll V_{bias}$$

$$d\Big|_{V_{bias}} = \sqrt{\frac{2\varepsilon V_{bias}}{eN}}; \ N = N_A \text{ ou } N_D = \text{net impurity of material}$$

$$N = 10^{+13} atoms / cm^3; \ V_{bias} = 3000 Volt;$$

$$d\Big|_{V_{bias} = 3000 Volt} = 2.2 mm$$

**High purity :** 

$$N_{A} ou \ N_{D} = 10^{+10} atoms / cm^{3}; \ V_{bias} = 1000Volt; \ \varepsilon = 16 \cdot \varepsilon_{0};$$
  

$$\varepsilon_{0} = 8.85 \cdot 10^{-12} F / m; F = Coulomb / Volt; \ e = 1.6 \cdot 10^{-19} Coulomb$$
  

$$d\Big|_{V_{bias} = 1000Volt} = 1.8 cm$$
  

$$d\Big|_{V_{bias} = 2000Volt} = 2.5 cm$$
  

$$d\Big|_{V_{bias} = 3000Volt} = 3.1 cm$$



.



**High Purity Germanium** 

Energy measurement of gammas  $(|N_A-N_D| \approx 10^{10} \text{ cm}^{-3}):$  $E_{gap} = 0.74 \text{ eV} \Rightarrow$ operation temperature : T= 77K $w_{eh}=2.98 \text{ eV}$ 

- ⇒excellent resolution
  - $E_{\gamma} = 1$  MeV,  $dE \cong 1$  keV
  - "High" photo peak efficiency

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## **Germanium detectors**

### **Operation temperature: T= 77K (Liquid Nitrogen)**

### **Configuration : co-axial**

#### **Electronics is mounted very close to the Crystal**









**PHC** 









## Euroball à Strasbourg

ll y a quelques années

### **Challenges in Nuclear Structure Physics**

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# The idea of γ-ray tracking



Figure 1.12: Doppler broadening

Previously scattered gammas were wasted. Technology is available now to track them.

## **Ge Tracking Array**



<u>Combination of:</u> •segmented detectors •digital electronics •pulse processing •tracking the γ-rays



Amount of germanium:

**36-fold segmentation** 



## What is AGATA?

derata deriver in the des (2012) 26 deriver in the deriver in the des (2012) 26 deriver in the deriver in the	A Criple Cryost - integration of 111 high resolu spectroscopy channels - cold FET technology for all si - of FET technology for all si - of technology for all si -	at tion ignals • So ma c • 36-fo • Tr inte	olid Sphere of Ge terial: Solid angle overage ~ 82 % old segmentation of crystal rack each gamma raction through the crystal Reconstruct and entangle gammas	13 Countries, > 4	0 Institutions	
Rates	3 MHz (Mγ= 1)	300 kHz (Mγ= 30)	180 hexagona	al crystals:	3 shapes	
Efficiency	43% (Mγ= 1)	28% (Mγ = 30)	3 fold cluster	s (cold FET): 60	) all equal 📑	•
Peak/Total	58% (Mγ= 1)	49% (M $\gamma$ = 30)	Inner radius	(Ge):	23.5 cm 🪺	Jun a

Angular Resolution

**IPHC** 

Pluridisciplinaire Hubert Culten

FWHM (1MeV), v/c = 50% ~6keV

~1°

Dr Helen Boston

AGATA ADVANCED GAMMA TRACKING ARRAY

362 kg

6480 segments





### **Segmentation of High Purity Ge crystal**

Divide the electrodes on the surface of the detector



#### Weighting field shows how the segmentation works



Figure 2.2: Weighting-potential distributions of the Core (a) and of segment A (b). Calculation conditions are the following: readout electrode at unit potential, all other electrode at zero potential, no space charge inside the material.

$$\begin{split} Q(t) &= -q \cdot \left[\phi_w\left(x_h(t)\right) - \phi_w(x_e(t))\right] \\ i(t) &= q \cdot \left[E_w(x_h(t)) \cdot v_h(t) - E_w(x_e(t)) \cdot v_e(t)\right] \end{split}$$

 $\phi_{\rm w}$  and  $E_{\rm w}$  are the weighting potential and the weighting field.



Michaël Ginsz, PhD thesis 2017





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Dr Helen Boston







**Dr Helen Boston** 

AGATE







Dr Helen Boston







Dr Helen Boston







Dr Helen Boston







Dr Helen Boston







Dr Helen Boston







Dr Helen Boston



### **Evolution of AGATA**



They think to have 60 detectors for AGATA by end 2023





### **Evolution of AGATA**







## **Conclusions** (nuclear detectors)

- High Z Scintillators are used for gamma spectroscopy, particular for anti Compton spectrometers
- Low Z (organic)-Scintillators used for particle detection/stopping
- Semiconductors: Si used for charged particle spectroscopy (alpha, protons, ... Fission fragments)
- Semiconductors: HP-Ge for high resolution and high efficient Gamma spectroscopy





Grand Collisionneur de Hadrons 7 TeV-protons + 7 TeV-protons

## rculate 11,245

times/sec

100's of millions of proton-proton collisions/second

CMS Centre @

Collisions are a billion times hotter han the centre of the sun and create new particles ( $E = mc^2$ )



CMS



proid Magnets Solenoid Magnet SCT Tracker Pixel Detector TR1 Tracker

Centre



#### ATLAS superimposed to



### **How huge are ATLAS and CMS?**



	<u>ATLAS</u>	<u>CMS</u>
Overall weight (tons)	7000	12500
Diameter	22 m	15 m
Length	46 m	22 m
Solenoid field	2 T	4 T









## **ALICE**





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### **Transverse slice through CMS detector**











# **CMOS Pixel detectors**

## MAPS = Monolithic Active Pixel Sensors

- For high resolution tracking



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# CMOS (Complementary metal-oxide-semiconductor) Detectors



Avantages of CMOS VLSI technology:

- µ-circuits integrated but still
- 100% fill factor
- Small sensitive volume ( $\approx$  épitaxial layer)  $\approx \! 10 \; \mu m$  thick detectors can be very thin
- Industrial production standards  $\Rightarrow$  « modestes » costs,



### Short coming:

**Circuitry of the electronic circuit is limited to only NMOS transistors.** 

Signal is created in p-epitaxial layer (lower doping):

 $Q\approx 80 \text{ e-h /} \mu m \Rightarrow signal < 1000 \text{ e}^-$ 

e<sup>-</sup> diffusent (thermiquement) to the jonction helped by reflexions at the boundaries formed by the p-weel and the substrat (higher doping)

**Diffusion time < 100ns** 

Charge is collected by the diode formed by the jonction n-well/p-epitaxial layer







# **Characteristics:**

- Pixel detector could be made very thin, low material budget!
- Thin epitaxial layer  $\rightarrow$  Small signals
- Small pixel size possible (10x10µm<sup>2</sup>) to obtain very good spatial resolution, but then limited space for electronic circuit available
- Only n-well Transistors
- Simple on pixel-cell electronics  $\rightarrow$  slow Read Out (next slide)





## Basic Read-Out Architecture only 3 transistors



Figure 3.8: Three transistor cell, (a) with a timing diagram showing the signal shape after passage of a particle, (b).



Tomasz Hemperek, PhD thesis



Rolling shutter readout concept where the integrated signal is read out and reset row by row:

- In his case all pixel outputs in the column are connected.
- Only one row of pixels is selected at a time for readout and/or reset.
- The column outputs can be multiplexed at the periphery in case of limited analog outputs.
- The recorded values can be digitized by external or internal components

Tomasz Hemperek, PhD thesis



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### **Typical layout of a MAPS chip**



courtesy of Ch. Hu-Guo / TWEPP-2010



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## Developments to improve performance for different experiments

- Several labs develop CMOS pixel sensors : Italy (INFN, Univ.), UK (RAL), CERN, France (IPHC, Saclay), USA, ...
- Increase and speed up collected charge by drift in depleted silicon
- Use of high resistivity silicon wafers
- Use of different (more complicated) CMOS processes
- Change layout to use the complete design potential (use of p-MOS transistors)
- Speed up Read Out architecture
- Large area (wafer size) devices (stitching)
  - Curved thin detector layers without additional support material





# Depleted Monolithic Active Pixels (HV-MAPS or D-MAPS)





### **Goals:**

- large signals
- fast charge collection by drift in a 50µm – 200µm thick depleted layer
- the use of PMOS and NMOS transistors in the pixel cell (full CMOS),
- The entire CMOS pixel electronics is placed inside the deep n-well.
- This way, the pixel contains only one deep n-well without any inactive
  secondary wells that could attract the signal charge and cause detection inefficiency.
- it is reversely biased with respect to vith the substrate from the front side.
- By applying high voltage reverse bias (>60V) it is possible to create a depletion depth of a few to tens of microns
- implementation in a commercial technology





#### VDD N N PW NW P-buried (PB) -50-300µm Very Deep Nwell (VDN) Cos particle track (~80 e'/µm) P-substrate HV 0V VDD Ν N N NW NIA PW N

-HV

P-buried (PB)

NW.

VDD

-HV

HWP

SiO<sub>2</sub> (BOX)

particle track (~80 e-/µm)

N

PW

particle track (~80 e-/µm)

0V

**P-substrate** 



**Depleted MAPS, HV-SOI** 

VDD

N

NW

Deep Pwell

-2-3µm

HWP

P-substrate

N

NWC

TCDS

Tomasz Hemperek, PhD thesis

N

(BOX = buried layer of silicon oxide)

#### **Depleted MAPS**,

Logic located outside collecting node



# **Building Vertex detectors with MAPS** STAR experiment at RHIC, BNL

First large scale application of MAPS in an experiement

## **2 layers of MAPS for pixel vertex detector**





(b) functional diagram of the chip

#### M. A. Szelezniak PhD thesis 2008



Figure 6.3: MIMOSTAR chip - layout, (a), and a functional schematic diagram, (b).



# STAR experiment at RHIC, BNL

#### First large scale application of MAPS in an experiement

## - 2 layers of MAPS for pixel vertex detector



356 M pixels in 2 layers ~0.16 m<sup>2</sup> R=28mm, 80mm Pixels size 20.7x20.7  $\mu$ m<sup>2</sup> X/X<sub>0</sub> = 0.39% for layer 1 Integration time 185.6  $\mu$ s



#### carbon fiber sector tubes (~ 200 µm thick)



#### de Strasbourg

## Building Vertex detectors with MAPS ALICE (LHC-CERN)

A Large Ion Collider Experiment

### **ITS2** layout

- 7 layers (inner/middle/outer): 3/2/2 from R = 23 mm to R = 400 mm
- 192 staves (IL/ML/OL): 48/54/90
- Ultra-lightweight support structure and cooling

#### 10 m<sup>2</sup> active silicon area, 12.5×10<sup>9</sup> pixels





Spatial resolution  $\approx 5 \, \mu m$ 

Integration time < 10 µs

high-resistivity silicon epitaxial layer



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## ALICE: MAPS OXFORD

- Improve impact parameter resolution by a factor of ~3 in  $(r-\phi)$  and ~5 in (z)
  - -Closer to IP: 39 mm  $\rightarrow$  21 mm (layer 0)
  - -Reduce beampipe radius: 29 mm  $\rightarrow$ 18.2 mm
  - -Reduce pixel size: (50  $\mu$ m x 425  $\mu$ m)  $\rightarrow$ O(30 µm x 30 µm)
  - -Reduce material budget: 1.14 %  $X_0 \rightarrow$ 0.3 % X<sub>0</sub> (inner layers)





- High tracking efficiency and p<sub>T</sub> resolution
  - Increase granularity and radial extension → 7 pixel layers
- Fast readout of Pb-Pb interactions at 50 kHz (now 1kHz) and 400 kHz in p-p interactions
- Rad hard to TID: 2.7 Mrad, NIEL: 1.7 x 10<sup>13</sup> 1 MeV n<sub>eq</sub> cm<sup>-2</sup> (safety factor 10)
- Fast insertion/removal for maintenance

## **Building Vertex detectors with MAPS** ALICE (LHC-CERN)

A Large Ion Collider Experiment

### ALPIDE — the Monolithic Active Pixel Sensor (MAPS) for ITS2





AMP COMP TH • Developed within the ITS2 project

#### Technology

- TowerJazz 180 nm CMOS Imaging Process
- High-resistivity (>  $1k\Omega$  cm) p-type epitaxial layer (25  $\mu$ m) on p-type substrate
- Small n-well diode (2 µm diameter), ~100 times smaller than pixel (~30 µm)
  → low capacitance (~fF)
- Reverse bias voltage (-6 V <  $V_{BB}$  < 0 V) to substrate to increase depletion zone around NWELL collection diode
- Deep PWELL shields NWELL of PMOS transistors
  → full CMOS circuitry within active area

#### **Key features**

- In-pixel amplification and shaping, discrimination and Multiple-Event Buffers (MEB)
- In-matrix data sparsification
- On-chip high-speed link (1.2 Gbps)
- Low total power consumption < 40 mW/cm<sup>2</sup>

Technology now used in other applications



ESE Electronics seminar by T. Kugathasan

#### Capture d'écran

ALICE ITS2 | CERN Detector Seminar | October 21st, 2022 | Felix Reidt (CERN)





- TowerJazz and the Detector Systems Centre (Rutherford Appleton Laboratory)
  - Deep P-layer to shield the PMOS transistors from epi layer
    - No charge loss occurs
    - Full CMOS ➡ Smart pixels possible
    - Not a CMOS standard process
  - Disadvantages
    - limited number of producers and non-standard CMOS process





- INMAPS on High Resistivity resistivity (> 1kΩ cm) p-type epi-layer 18-40 µm thick
  - Moderate reverse bias to back bias to increase depletion zone around NWELL diode → some charge collection by drift
  - Small n-well collecting diodes small Cin
  - Radiation tolerance (TID) to 700 krad (= 1/1500 of HL-LHC-pp)

R. Turchetta, W. Snoeys

D. Bortoletto Academic Training 2016

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# ALICE (LHC-CERN) ITS 2

A Large Ion Collider Experiment





## ITS3

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# 2 × 26.88 µm 2 x 29.24 µm metal-layers 25 µm epitaxial laver substrate 14 µm Schematic cross section of ALPIDE





Magnus Mager (CERN) | ALICE ITS3 | CERN detector seminar | 24.09.2021 | 9





Magnus Mager (CERN) | ALICE ITS3 | CERN detector seminar | 24.09.2021 | 26



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CMS Experiment at the LHC, CERN Data recorded: 2016-Oct-14 09:56:16.733952 GMT Run / Event / LS: 283171 / 142530805 / 254

## First Tracker layer R~3cm ~0.7 hits/BX/mm2 = 2.8 GHz/cm2





# 3D sensors

- Advantages
  - Decouple thickness from electrode distance
  - Lower depletion voltage, less power dissipation
  - Smaller drift distance, less trapping
- Disadvantage
  - More complex production process
  - Lower yield, higher costs
  - Higher capacitance (more noise)



- 3D is the most radiation hard technology to-day
- Similar performance than planar sensors, but less demanding in terms of bias voltage and cooling.
- For the HL-LHC we need :
  - More radiation hard (innermost layer(s), 1-2E16 n<sub>eq</sub>/cm<sup>2</sup>)
  - Smaller pixels (compatible with new readout chip,  $50 \mu m 25 \mu m$ )
  - Thinner (reduce cluster size/merging, 200 μm 100 μm)



# **3D Silicon**



4 Mauro Dinardo, Università degli Studi di Mila Capture d'écran



# 4D Detectors (x,y,z and time)



Tracking z-resolution can be larger than vertex-separation: Ambiguous Track-to-vertex association



N. Cartiglia, INFN, Hiroshima Conference 2017

Timing at each point along the track:

- Massive simplification of patter recognition
- Faster tracking algorithm
- Even in very dense environments by using only "time compatible points »

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## **The Time Structure of Crossing Bunches**

- In addition to extent in z, there is an extent of the bunch crossing in time
- For nominal HL-LHC optics the core of the bunches pass through each other in ~300 ps
- When bunches overlap entirely, achieve maximum spread in z and maximum pileup density
- Normally an experiment only sees the integral of this distribution over time



**Fermilab** 

Need to discriminate vertices with time spread of ~180 ps, must have time track timing [cm]

resolution significantly smaller than beamspot spread so that tracks cluster in time.



Figure 1.2: Left: Simulated and reconstructed vertices in a 200 pileup event assuming a MIP timing detector covering the barrel and endcaps. The vertical lines indicate 3D-reconstructed vertices, with instances of vertex merging visible throughout the event display. Right: Rate of tracks from pileup vertices incorrectly associated with the primary vertex of the hard interaction normalized to the total number of tracks in the vertex.



## **Using the Time-at-vertex in Reconstruction**

- With the track-time at distance of closest approach
  it becomes possible to cluster tracks in 2D into vertices
- This significantly increases the distance between vertices and hence makes them harder to confuse
- CMS Simulation <u> = 200 Simulated Vertices 3D Reconstructed Vertices 0.6 4D Reconstructed Vertices 4D Tracks 0.4 0.2 0 -0.2 -0.4-10 -5 5 n 10 z (cm)

#### **CMS Simulation**

<µ>	4D Merged Vertex Fraction	3D Merged Vertex Fraction	Ratio of 3D/4D
50	0.5%	3.3%	6.6
200	1.5%	13.4%	8.9



- Expect 5-10x improvement in vertex merging rate (achieved 9x)
- Expect 3-5x reduction in track-vertex association false positives (achieve ~3x)



lutetium-yttrium orthosilicate crystals activated with cerium (LYSO:Ce) read out with SiPMs. The

The barrel timing layer will cover the pseudorapidity region up to |h| = 1.48 with a total active surface of about 40 m2.

The fundamental detecting cell will consist of a thin LYSO:Ce crystal with about 12→12 mm2 cross-section coupled to a 4x4 mm2 SiPM.

The crystal thickness will vary between about 3.7 mm (|h| < 0.7) and 2.4 mm (|h| > 1.1),



Figure 2.4: Top left: Set of  $11 \times 11 \times 3 \text{ mm}^3$  LYSO:Ce crystals with depolished lateral faces, before and after Teflon wrapping. Bottom left:  $6 \times 6 \text{ mm}^2$  HPK SiPMs glued on LYSO crystals. Right: Crystal+SiPM sensors plugged on the NINO board used for test beam studies.





## **LGADs**

Nicolo Cartiglia

 Achieve ≈10 ps timing resolution with Si detectors using charge amplification with Low-Gain Avalanche Detectors



Lots of R&D, DC and AC coupled, chip design, test beams Both ATLAS and CMS but also for Higgs factories etc





### HL-LHC necessitates upgrades to the CMS detector

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#### Thorben Quast | Pisa Meeting 2022, 25 May 2022



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# **Technology** Choices



Dissipated power ~250 kW

Removed with two-phase CO2 cooling operated at -35 C

Geometry slightly adjusted since the <u>TDR release</u>



### Idea: HGCAL will be 3D imaging calorimeter with timing capabilities 8





# Lateral Structure, Cassettes

- Silicon and scintillator modules assembled into
- cassettes
- Supported and cooled by copper cooling plate
- Data from modules collected by motherboards
- Cassettes house all services and DC2DC converters



# Silicon Modules

- Glued stack of baseplate, sensor and readout hexaboard
- baseplates are made of CuW in CE-E, PCB in CE-H
- Relative alignment within
  ~50um achieved with gantry based automated assembly
- Electrical connections are done with wire-bonds





signal bonds shield bonds backside HV bonds








### **Dreams in space**





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### AMS → AMS100

It took 600 Physicists and Engineers from 16 Countries and 60 Institutes

S. Schael RWTH Aachen University November 2022

> 17 years to construct the Alpha Magnetic Spectrometer. 300,000 electronic channels 5m x 4m x 3m 🧪 7 tons Silicon TRD layer TOF 1 Magnet 7 Silicon layers **TOF 3**, **Radiators** RICH 11,000 Photo Sensors Silicon layer ECAL

We have to start now to work on the next generation magnetic spectrometer in space !



S. Schael RWTH Aachen University November 2022



acceptance by a factor 1000.

PHC

## AMS $\rightarrow$ AMS100



GeV

TeV

PeV

EeV

ZeV 13

Swordy KG 2011

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### **AMS 100**

S. Schael RWTH Aachen University November 2022







Nucl.Instrum.Meth.A 1040 (2022) 167215 • Proceedings of: VCI2022



S. Schael RWTH Aachen University November 2022

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AMS-100 Solenoid a non-insulated coil

90 km of High Temperature Superconducting Tape

Thickness: 18 x 0.04 mm = 0.72 mm !



Stack of 18 Tapes 12 mm wide; Fujikura, 700 A @ 77K, SF



S. Schael RWTH Aachen University

## AMS 100

# AMS-100: A Magnetic Spectrometer

#### Table of properties for the AMS-100 main solenoid and compensation coil. Compensation Combined Unit Main Coil radius 2.0 4.0 m Coil length 6.0 1.5 m Tape width 12 12 mm Stabilizer AI-6063 AI-6063 Cable thickness 2.85 2.85 mm Cable width 16 16 mm Layers 1 1 Turns 376 94 Inductance 286 114 287 mH Number of tapes 18 18 Total tape length 85 43 128 km **Operating current** 10.0 -10.0kA Cable mass 1090 545 1635 kg Stored Energy 14.3 14.4 MJ 5.7 kJ/kg Energy Density\* 14 11 9 \*Considering only the mass of the cable.



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de Strasbourg

S. Schael RWTH Aachen University November 2022

- In 2005 NASA canceled the AMS-02 Space Shuttle Flight.
- At RWTH Aachen a concept for a balloon experiment (PEBS) was developed to measure cosmic ray positrons.
- A new scintillating fiber tracker with SiPM readout was the key element for the tracking system.
- In 2008 the group of T. Nakada, EPFL joined the team.
- In 2010 a prototype (PERDAIX) was launched from Kiruna, Sweden. 300 000 protons and Helium nuclei were recorded at an altitude of 34 km.
- The paper describing this new SciFi detector was published in Nucl. Instrum. Meth.A 622 (2010) 542-554 (10.1016/j.nima.2010.07.059).
- In 2014 the LHCb Upgrade I TDR was published, describing a 360 m<sup>2</sup> version of this detector build from 11,000 km of fiber.













#### **Positrons in Cosmic Rays**



S. Schael RWTH Aachen University November 2022 46



### **Résumé**

### This was a very short and limited snapshot of some of the many ideas and developments on detectors.



Ulrich.Goerlach@i	phc.cnrs.fr, ASP	<b>Particle detectors</b>
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atitut Pluridisciplinaire Hubert Cuiten







### Resolution



Ulrich.Goerlach@iphc.cnrs.fr, ASP Particle detectors

$$N_{hv} = \frac{E}{w}; \ dN_{hv} = \sqrt{N_{hv}} = \sqrt{\frac{E}{w}}$$

Statistics strictly Poisson  $\Rightarrow \sigma^2 = \mu$ ;

$$dE / E = dN_{hv} / N_{hv} \sim \frac{1}{\sqrt{N_{hv}}}$$

**Nal**:  $w \approx 25 eV / photon_{scint} \Rightarrow 40000 hv / MeV$ 

Incomplete collection of scintillation photons and finite quantum efficiency will reduce the mean number of photo-electrons

$$N_{pe} = N_{hv} \times \varepsilon_{collection} \cdot \varepsilon_{quantic};$$

$$dN_{pe} = \sqrt{N_{pe}} = \sqrt{N_{hv}} \times \varepsilon_{coll.} \cdot \varepsilon_{quant.}$$

$$\varepsilon_{coll.} \approx 0.2 - 0.8; \varepsilon_{quant.} \approx 0.2 (PM)$$

$$dE / E = dN_{pe} / N_{pe} \approx \frac{1}{\sqrt{N_{pe}}} = \frac{1}{\sqrt{N_{hv}} \times \varepsilon_{coll.} \cdot \varepsilon_{quant.}}$$

$$F \approx 1; \varepsilon_{coll.} \approx 0.4; \varepsilon_{quant.} \approx 0.2 (PM)$$

$$\Rightarrow dE / E = \sigma_{E} / E \approx 1.5\% \text{ à } 1.333 \text{ MeV}$$

$$R = 2.35 \times 1.5\% = 3.6\% \xrightarrow{\text{experimental}} (5 - 8)\%$$



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$$N_{eh} = \frac{E}{w} \varepsilon_{collection}$$
HP-Ge detector
$$dN_{eh} = \sqrt{N_{eh}} = \sqrt{\frac{E}{w}} \varepsilon_{collection}$$
Statistics : Poisson
$$\Rightarrow \sigma^{2} = \mu; \quad \mu = \text{mean}; \sigma^{2} = \text{variance}$$

$$dE / E = dN_{eh} / N_{eh} \sim \frac{1}{\sqrt{N_{eh}}} = \frac{1}{\sqrt{\frac{E}{w}} \varepsilon_{collection}}$$

$$\varepsilon_{collection} \approx 100\%; \quad w = 2.98 \, eV \quad E = 1 \, MeV$$

$$\Rightarrow dE / E \approx 0.0017; \text{ Resolution } R = 2.35 \times dE / E = 0.4\%$$
Fano factor:
$$\sigma^{2} = F_{ano}\mu;$$

$$F_{ano} \approx 0.12 (Ge, Si); \quad \sqrt{0.12} = 1/2.9$$

$$dE / E = dN_{eh} / N_{eh} \sim \frac{\sqrt{F}}{\sqrt{N_{eh}}} = \frac{1}{\sqrt{\frac{E}{wF}} \varepsilon_{collection}}}$$

$$dE / E = 0.0006; \text{ Resolution } R = 2.35 \times dE / E = 0.14\%$$
Comparison with  $NaI$ :

 $w = 25 eV / photon_{scint}$  Light collection: 0.5 PM :  $Q.E. \approx 0.20$  $dE / E \approx 1.6\%$  Resolution  $R = 2.35 \times dE / E = 3,7\%$  à 1MeV

#### de strasbaue The EUROBALL Cluster Detector 10kg HPGe





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#### cle detectors



### **3D Silicon**

HL-LHC operation conditions	Sensor design constraints		
Luminosity 7.5x10 <sup>34</sup> /(cm <sup>2</sup> ·s) $\rightarrow$ up to <b>200 events/25 ns</b> bunch crossing	Maintain occupancy at $\infty$ level and increase spatial resolution $\rightarrow$ pixel size $\times 6$ smaller then present pixels - 25x100 $\mu$ m <sup>2</sup> (current detector in CMS 100x150 $\mu$ m <sup>2</sup> )		
CMS baseline choice: replace pixel layer closer to beamline at integrated fluence $\sim 1.9 \times 10^{16} n_{eq}/cm^2$ (end of <i>"Run5"</i> , i.e. after ~6 years of operation) $\rightarrow$ electron mean free path greatly reduced (also damaged readout ASIC at ~1 Grad)	Reduce electrodes distance (L) to increase electric field an thus the signal $\rightarrow$ thin planar or 3D columnar technologies		

#### 3D silicon sensors made by

- Fondazione Bruno Kessler-FBK (Trento, Italy), n-in-p sensors on 150 mm FZ wafers in collaboration with INFN
- Centro Nacional Microtecnologia-CNM (Barcelona, Spain), n-in-p sensors on 100 mm FZ wafers



C. Da Vià et al., NIMA (2012)

2 Mauro Dinardo, Università degli Studi di Mila Capture d'écran



### **Inspiration for ITS3**





- Observations:
  - Si makes only **1/7**<sup>th</sup> of total material
  - irregularities due to support/ cooling

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## **Inspiration for ITS3**





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# **ITS3** the idea (2): build wafer-scale sensors





- Chip size is traditionally limited by CMOS manufacturing ("reticle size")
  - typical sizes of few cm<sup>2</sup>
  - modules are tiled with chips connected to a flexible printed circuit board



- New option: stitching, i.e. aligned exposures of a reticle to produce larger circuits
  - actively used in industry
  - a 300 mm wafer can house a sensor to equip a full half-layer
  - requires dedicated sensor design

Courtesy: R. Turchetta,

**Rutherford Appleton Laboratory** 



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Ulrich Goorlach@inhc enrs fr ASP Particle detectors

# High Granularity for Particle Flow



### CMS uses particle flow algorithms to improve on jet energy resolution

- reconstruct every particle in a jet
- For each particle use the detector with best energy/ momentum measurement
- High granularity is key for correct assignment of energy deposits to tracks



#### **Compact Muon Solenoid**





### **Conductor Testing: Single- and Multi-Tape Samples**

- Single tapes have been extensively characterized
- Many short samples of Al-alloy stabilized multi-tape HTS conductors are in preparation.
- Few-tape samples in good agreement with expectations.
- Next: more tapes, bending, micro-meteorite impact testing, etc.











A large international team from several institutes, including EPFL and RWTH Aachen, constructed the LHCb SciFi Tracker in the past years.



